研究报告

茄子光系统Ⅱ的热胁迫特性

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以耐热性较弱的黑贝一号圆茄和耐热性较强的黑贝二号圆茄为试材,热胁迫处理后采用植物效率仪PEA进 行快速叶绿素荧光诱导曲线及其参数测定. 结果表明: 当温度高于40 ℃, PSⅡ结构受热胁迫影响较为敏感, 表现 为初始荧光 $F_{\rm o}$ 缓慢上升;PSII原初光化学效率 $F_{\rm v}/F_{\rm m}$ 和 $\Delta F/F_{\rm m}$ '大幅度下降,且黑贝二号 $F_{\rm v}/F_{\rm m}$ 的半衰时间 T_{50} 和 Δ F/F_m '的半衰温度 t_{50} 分别大于黑贝一号. 较高的热胁迫剂量(48℃处理5 min或44℃处理20~30min)下,快速荧 光诱导动力学曲线呈现0KJIP型,在700μs处出现与放氧复合体失活有关的K相. 黑贝一号在44 ℃下处理20 min才有 Email Alert K相出现,黑贝二号则晚10 min出现.与35℃相比,在48℃,特别是在52℃的较高剂量热胁迫下,Strasser能量流 动模型参数中的DI₀/RC有大幅度地增加,体现了热耗散对PSⅡ的较强保护能力. 随着热胁迫温度的升高和热胁迫时 ▶浏览反馈信息 间的延长,两品种的无活性中心 F_{vi}/Fv 显著增加.

关键词 热胁迫 叶绿素荧光参数 光系统 II 茄子 分类号

Heat stress characteristics of photosystem II in eggplant

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Abstract

With lower-and higher heat-resistant varieties of eggplant (Solanum melongena L.) Heibei I and Heibei II as test materials, and by using Plant Efficiency Analyzer (PEA) from Hansatech, this paper measured the fast chlorophyll a fluorescence transient and its parameters. The results showed that PS II construction became more sensitive to heat stress when ambient temperature was higher than 40 $^{\circ}$ C. The F_{o} went up slowly, and F_{v}/F_{m} and $\Delta F/F_{m}$ came down dramatically.

Heibei II had a longer semi-attenuation temperature of $F_{\rm v}/F_{\rm m}$ (${\rm T}_{\rm 50}$) and $\Delta F/F_{\rm m}$ (${\rm t}_{\rm 50}$) than Heibei

I . Under strong heat stress (5 min at 48 $^{\circ}$ C or 20-30 min at 44 $^{\circ}$ C), the K-step in relation to the inactivation of oxygen-evolving complex appeared in fluorescence rise at about 700 µs, and the regular O-J-I-P transient was transformed to O-K-J-I-P one. The K-phase of Heibei I and Heibei II appeared when the treatment time was up to 20 and 30 minutes at 44 °C, respectively. In comparing with 35 °C heat treatment, the DI_o/RC in the parameters of Strasser's specific energy fluxes model was increased by a great extent under 48 °C or more heat stress, reflecting a strong safeguard of energy dissipation to PS II. When the temperature of heat stress increased from 35 $^{\circ}$ C to 52 $^{\circ}$ C, the $F_{v,i}/F_{v,j}$ of PS II silent reaction centers of Heibei I and Heibei II increased remarkably.

Key words heat stress chlorophyll fluorescence parameter photosystem II eggplant (Solanum melongena L.)

DOI:

扩展功能

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